

# 2SJ586

Silicon P Channel MOS FET  
High Speed Switching

# HITACHI

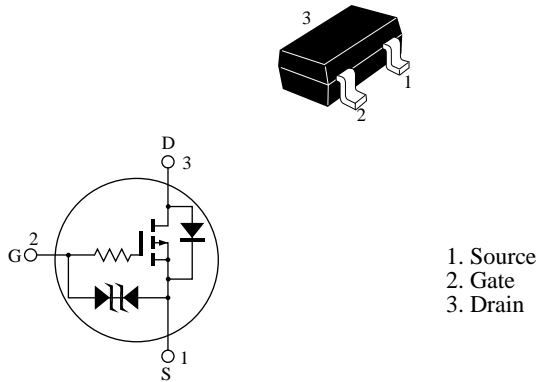
ADE-208-771A (Z)  
2nd.Edition.  
June 1999

## Features

- Low on-resistance  
 $R_{DS} = 4.1$  typ. ( $V_{GS} = -4$  V,  $I_D = -50$  mA)  
 $R_{DS} = 6.0$  typ. ( $V_{GS} = -2.5$  V,  $I_D = -50$  mA)
- 2.5 V gate drive device.
- Small package (CMPAK)

## Outline

CMPAK



## Absolute Maximum Ratings (Ta = 25°C)

Item	Symbol	Ratings	Unit
Drain to source voltage	$V_{DSS}$	-20	V
Gate to source voltage	$V_{GSS}$	±10	V
Drain current	$I_D$	-100	mA
Drain peak current	$I_{D(pulse)}$ <sup>Note 1</sup>	-400	mA
Body-drain diode reverse drain current	$I_{DR}$	-100	mA
Channel dissipation	Pch <sup>Note 2</sup>	300	mW
Channel temperature	Tch	150	°C
Storage temperature	Tstg	-55 to +150	°C

Note: 1. PW 10 μs, duty cycle 1%

2. Value on the alumina ceramic board (12.5x 20 x0.7 mm)

## Electrical Characteristics (Ta = 25°C)

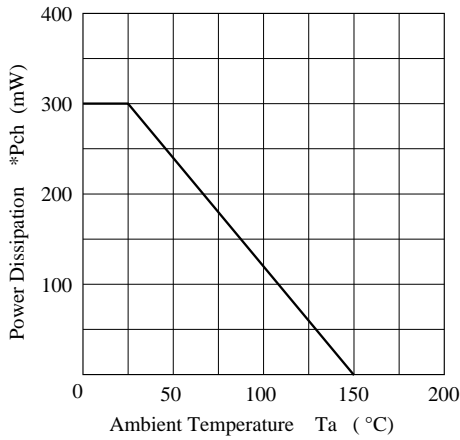
Item	Symbol	Min	Typ	Max	Unit	Test Conditions
Drain to source breakdown voltage	$V_{(BR)DSS}$	-20	—	—	V	$I_D = -100 \mu A, V_{GS} = 0$
Gate to source breakdown voltage	$V_{(BR)GSS}$	±10	—	—	V	$I_G = \pm 100 \mu A, V_{DS} = 0$
Gate to source leak current	$I_{GSS}$	—	—	±5	μA	$V_{GS} = \pm 8 V, V_{DS} = 0$
Zero gate voltage drain current	$I_{DSS}$	—	—	-1	μA	$V_{DS} = -20 V, V_{GS} = 0$
Gate to source cutoff voltage	$V_{GS(off)}$	-0.8	—	-1.8	V	$I_D = -10 \mu A, V_{DS} = -5 V$
Static drain to source on state resistance	$R_{DS(on)}$	—	4.1	5.0		$I_D = -50 mA, V_{GS} = -4 V$ <sup>Note 3</sup>
	$R_{DS(on)}$	—	6.0	8.5		$I_D = -50 mA, V_{GS} = -2.5 V$ <sup>Note 3</sup>
Forward transfer admittance	$ y_{fs} $	94	144	—	mS	$I_D = -50 mA, V_{DS} = -10 V$ <sup>Note 3</sup>
Input capacitance	Ciss	—	28	—	pF	$V_{DS} = -10 V$
Output capacitance	Coss	—	21	—	pF	$V_{GS} = 0$
Reverse transfer capacitance	Crss	—	7	—	pF	f = 1 MHz
Turn-on delay time	$t_{d(on)}$	—	30	—	ns	$I_D = -50 mA, V_{GS} = -4 V$
Rise time	$t_r$	—	90	—	ns	$R_L = 200$
Turn-off delay time	$t_{d(off)}$	—	87	—	ns	
Fall time	$t_f$	—	97	—	ns	

Note: 3. Pulse test

4. Marking is CP

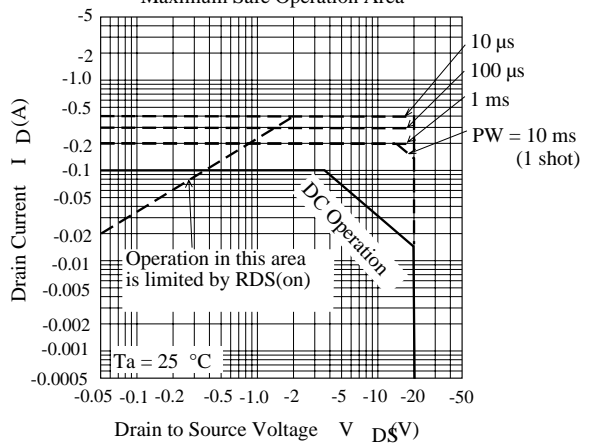
# Main Characteristics

Power vs. Temperature Derating



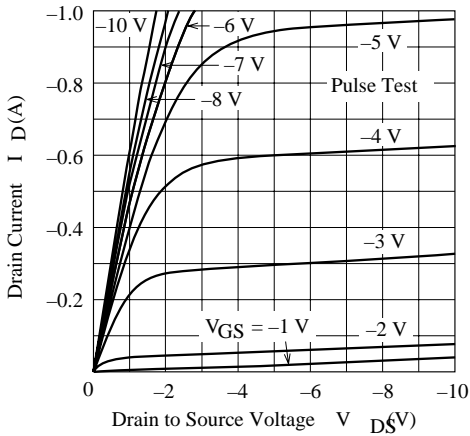
\*Value on the alumina ceramic board.(12.5x20x0.7mm)

Maximum Safe Operation Area

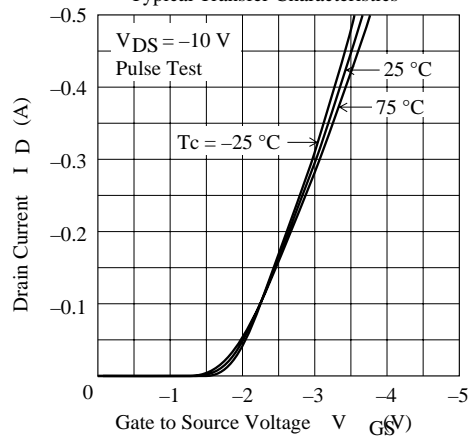


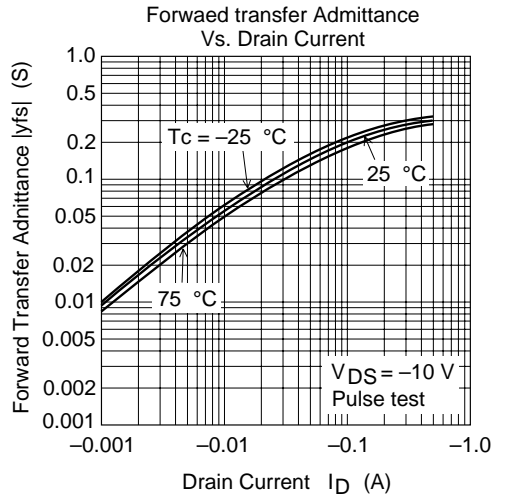
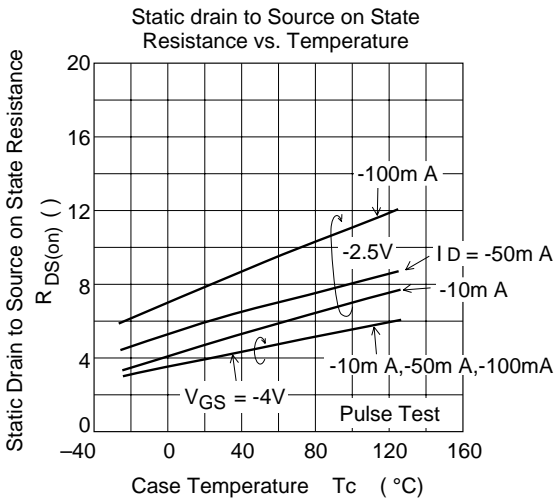
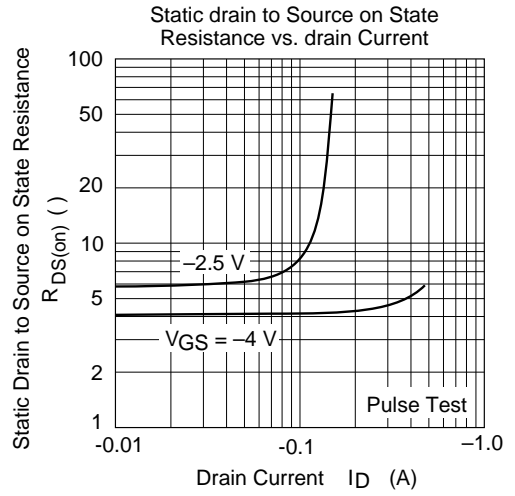
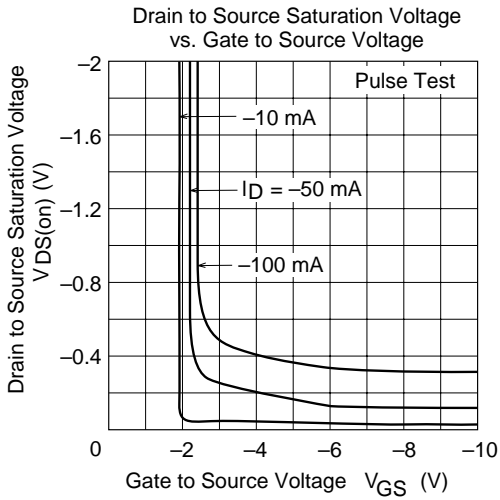
Value on the alumina ceramic board.(12.5x20x0.7mm)

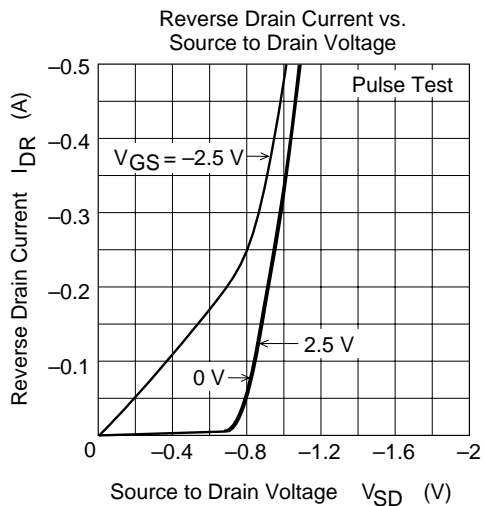
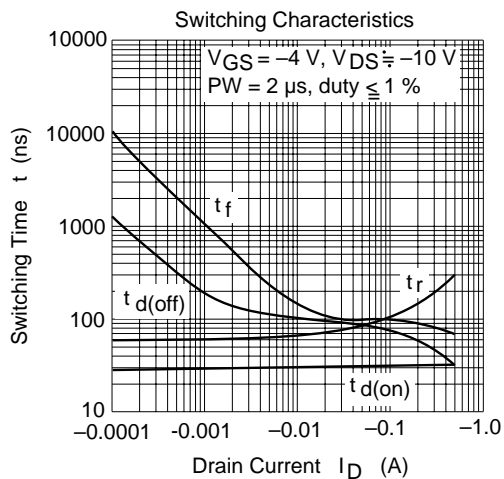
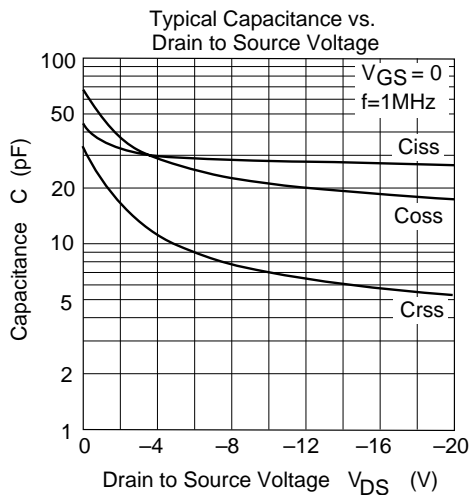
Typical Output Characteristics



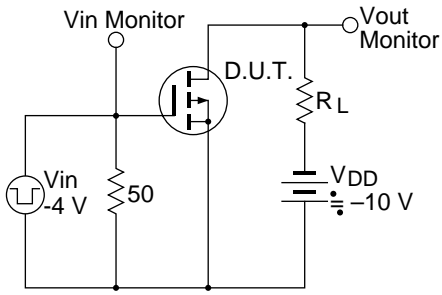
Typical Transfer Characteristics



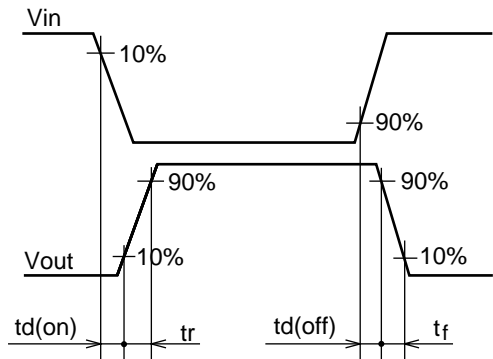




Switching Time Test Circuit



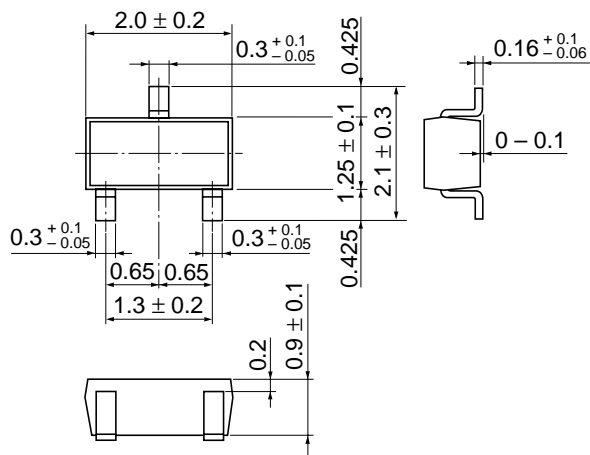
Waveforms



## Package Dimensions

As of January, 2001

Unit: mm



Hitachi Code	CMPAK
JEDEC	—
EIAJ	Conforms
Mass (reference value)	0.006 g

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